

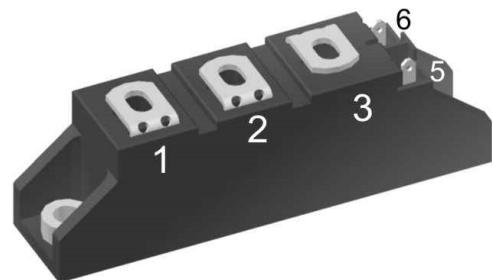
# Thyristor Module

$V_{RRM} = 2 \times 800 \text{ V}$   
 $I_{TAV} = 49 \text{ A}$   
 $V_T = 1.34 \text{ V}$

## Phase leg

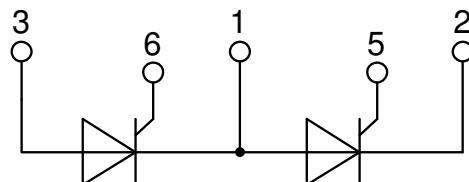
### Part number

**MCC44-08io8B**



Backside: isolated

**E72873**



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al<sub>2</sub>O<sub>3</sub>-ceramic

### Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: TO-240AA

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

### Terms & Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office.

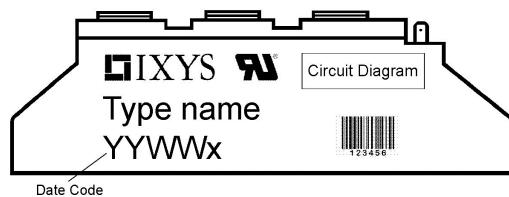
Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office.

Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

- to perform joint risk and quality assessments;
- the conclusion of quality agreements;
- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

Thyristor			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			900	V
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			800	V
$I_{R/D}$	reverse current, drain current	$V_{R/D} = 800 V$ $V_{R/D} = 800 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		100 5	$\mu A$ mA
$V_T$	forward voltage drop	$I_T = 100 A$	$T_{VJ} = 25^\circ C$		1.34	V
		$I_T = 200 A$			1.75	V
		$I_T = 100 A$ $I_T = 200 A$	$T_{VJ} = 125^\circ C$		1.34 1.80	V
$I_{TAV}$	average forward current	$T_C = 85^\circ C$	$T_{VJ} = 125^\circ C$		49	A
$I_{T(RMS)}$	RMS forward current	180° sine			77	A
$V_{T0}$ $r_T$	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 125^\circ C$		0.85 3.7	V $m\Omega$
$R_{thJC}$	thermal resistance junction to case				0.53	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.20		K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ C$		180	W
$I_{TSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$		1.15	kA
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 V$		1.24	kA
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 125^\circ C$		980	A
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 V$		1.06	kA
$I^2t$	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$		6.62	$kA^2s$
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 V$		6.40	$kA^2s$
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 125^\circ C$		4.80	$kA^2s$
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 V$		4.63	$kA^2s$
$C_J$	junction capacitance	$V_R = 400 V$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ C$	54		pF
$P_{GM}$	max. gate power dissipation	$t_p = 30 \mu s$	$T_C = 125^\circ C$		10	W
		$t_p = 300 \mu s$			5	W
$P_{GAV}$	average gate power dissipation				0.5	W
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 125^\circ C; f = 50 \text{ Hz}$ repetitive, $I_T = 150 A$			150	$A/\mu s$
		$t_p = 200 \mu s; di_G/dt = 0.45 A/\mu s$				
		$I_G = 0.45 A; V = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 49 A$			500	$A/\mu s$
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$	$T_{VJ} = 125^\circ C$		1000	$V/\mu s$
		$R_{GK} = \infty$ ; method 1 (linear voltage rise)				
$V_{GT}$	gate trigger voltage	$V_D = 6 V$	$T_{VJ} = 25^\circ C$		1.5	V
			$T_{VJ} = -40^\circ C$		1.6	V
$I_{GT}$	gate trigger current	$V_D = 6 V$	$T_{VJ} = 25^\circ C$		100	mA
			$T_{VJ} = -40^\circ C$		200	mA
$V_{GD}$	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 125^\circ C$		0.2	V
$I_{GD}$	gate non-trigger current				10	mA
$I_L$	latching current	$t_p = 10 \mu s$ $I_G = 0.45 A; di_G/dt = 0.45 A/\mu s$	$T_{VJ} = 25^\circ C$		450	mA
$I_H$	holding current	$V_D = 6 V$ $R_{GK} = \infty$	$T_{VJ} = 25^\circ C$		200	mA
$t_{gd}$	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$ $I_G = 0.45 A; di_G/dt = 0.45 A/\mu s$	$T_{VJ} = 25^\circ C$		2	$\mu s$
$t_q$	turn-off time	$V_R = 100 V; I_T = 150 A; V = \frac{2}{3} V_{DRM}$ $T_{VJ} = 100^\circ C$ $di/dt = 10 A/\mu s$ $dv/dt = 20 V/\mu s$ $t_p = 200 \mu s$		150		$\mu s$

Package TO-240AA			Ratings		
Symbol	Definition	Conditions	min.	typ.	max.
$I_{RMS}$	$RMS$ current	per terminal			200
$T_{VJ}$	virtual junction temperature		-40		125
$T_{op}$	operation temperature		-40		100
$T_{stg}$	storage temperature		-40		125
<b>Weight</b>				81	g
$M_D$	mounting torque		2.5		4
$M_T$	terminal torque		2.5		4
$d_{Spp/App}$	creepage distance on surface / striking distance through air		terminal to terminal	13.0	9.7
$d_{Spb/Abp}$			terminal to backside	16.0	16.0
$V_{ISOL}$	isolation voltage	$t = 1$ second $t = 1$ minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA		3600 3000
					V V



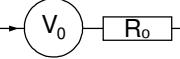
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCC44-08io8B	MCC44-08io8B	Box	36	452947

Similar Part	Package	Voltage class
MCMA50P1200TA	TO-240AA-1B	1200
MCMA65P1200TA	TO-240AA-1B	1200

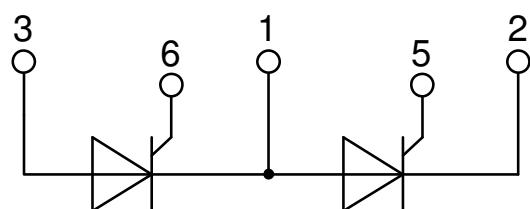
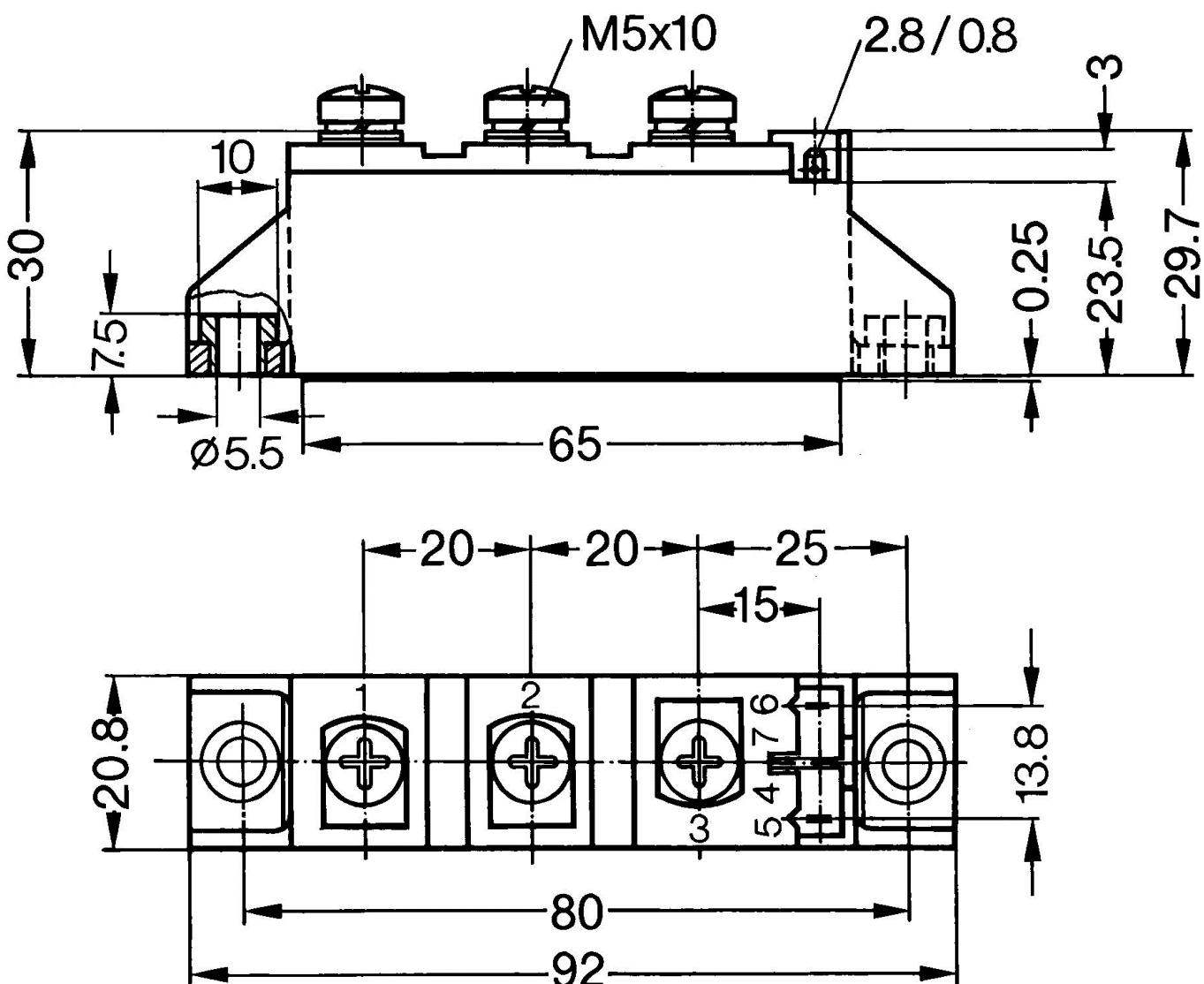
### Equivalent Circuits for Simulation

\* on die level

$T_{VJ} = 125$  °C

	Thyristor	
$V_{0\max}$	threshold voltage	0.85
$R_{0\max}$	slope resistance *	4.1

## Outlines TO-240AA



## Thyristor

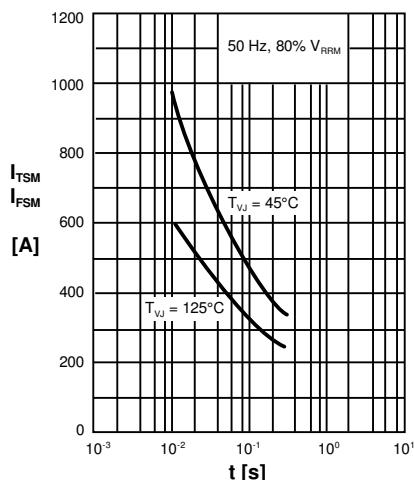


Fig. 1 Surge overload current  
 $I_{TSM}$ ,  $I_{FSM}$ : Crest value,  $t$ : duration

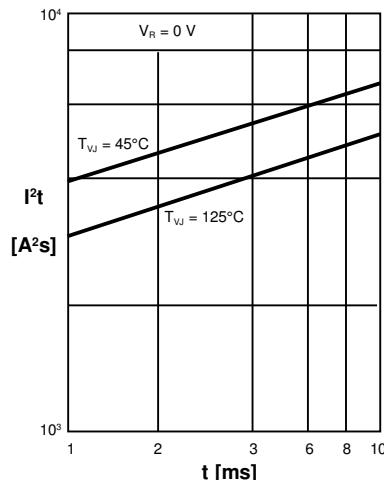


Fig. 2  $I^2t$  versus time (1-10 ms)

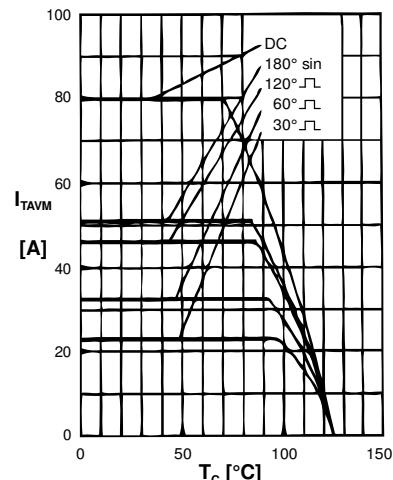


Fig. 3 Maximum forward current at case temperature

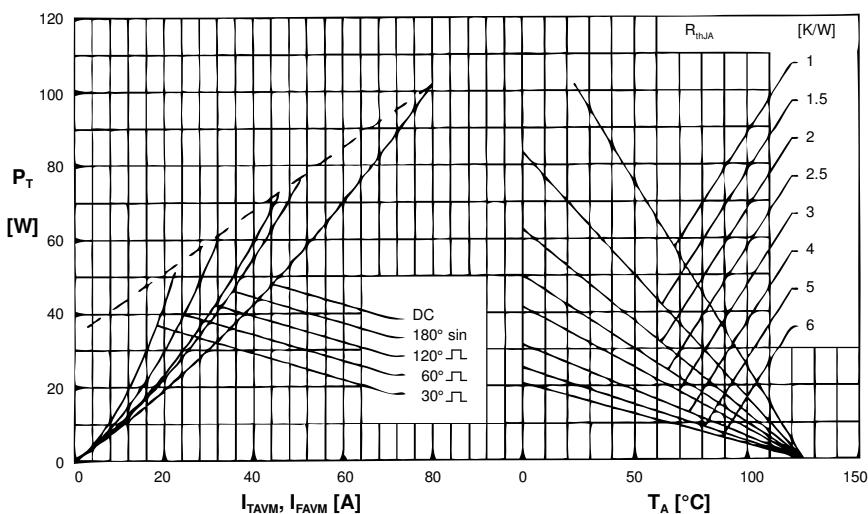


Fig. 4 Power dissipation vs. onstate current and ambient temperature (per thyristor/diode)

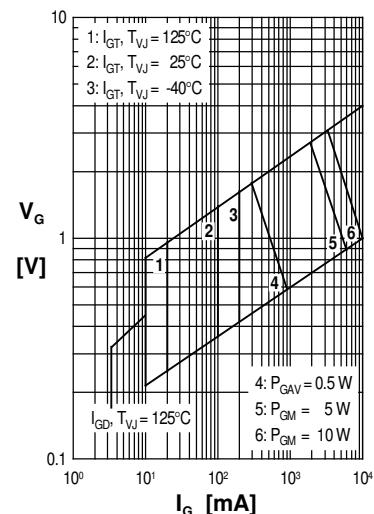


Fig. 5 Gate trigger characteristics

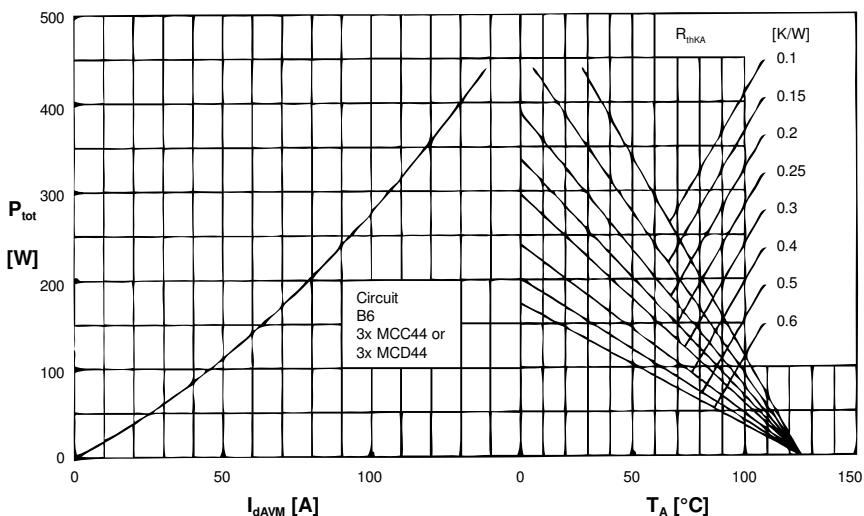


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature  
 Circuit B6  
 3x MCC44 or  
 3x MCD44

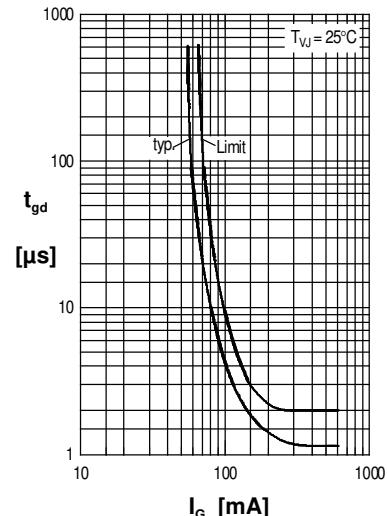


Fig. 7 Gate trigger delay time

## Thyristor

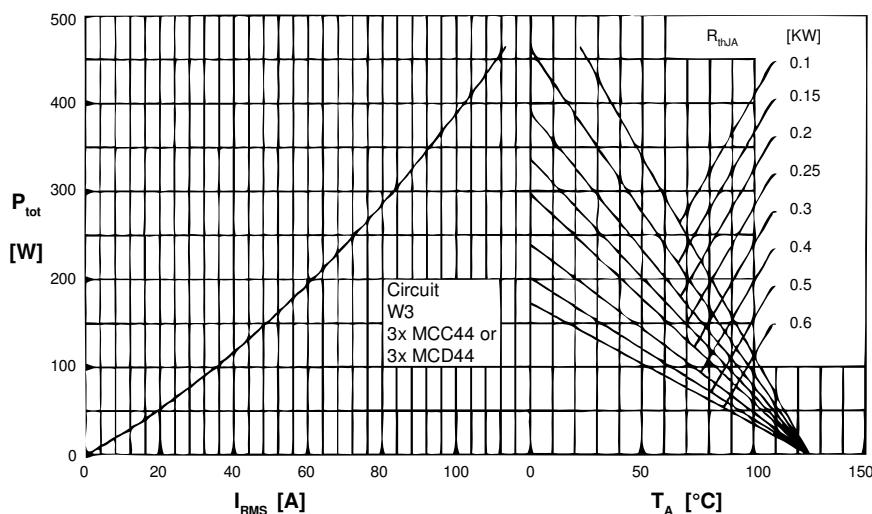


Fig. 8 Three phase AC-controller: Power dissipation versus RMS output current and ambient temperature

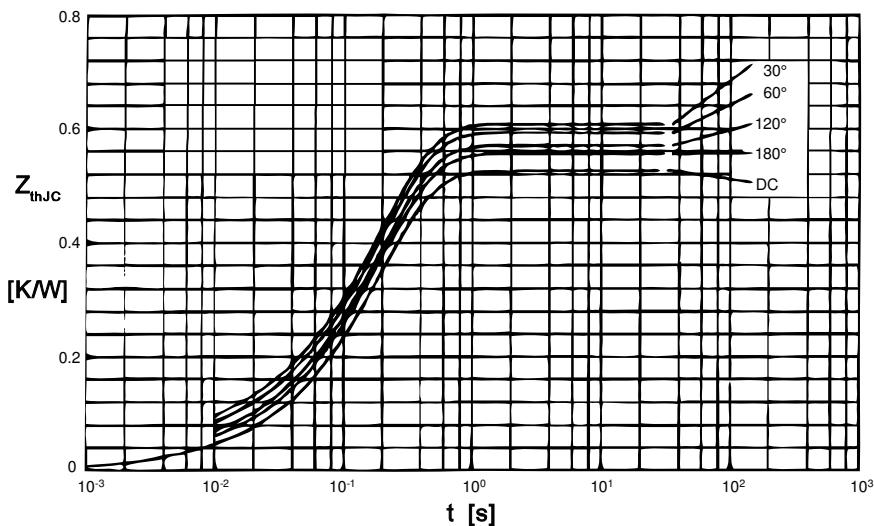


Fig. 9 Transient thermal impedance junction to case (per thyristor)

$R_{thJC}$  for various conduction angles d:

d	$R_{thJC}$ [K/W]
DC	0.53
180°	0.55
120°	0.58
60°	0.60
30°	0.62

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ [K/W]	$t_i$ [s]
1	0.015	0.0035
2	0.026	0.0200
3	0.489	0.1950

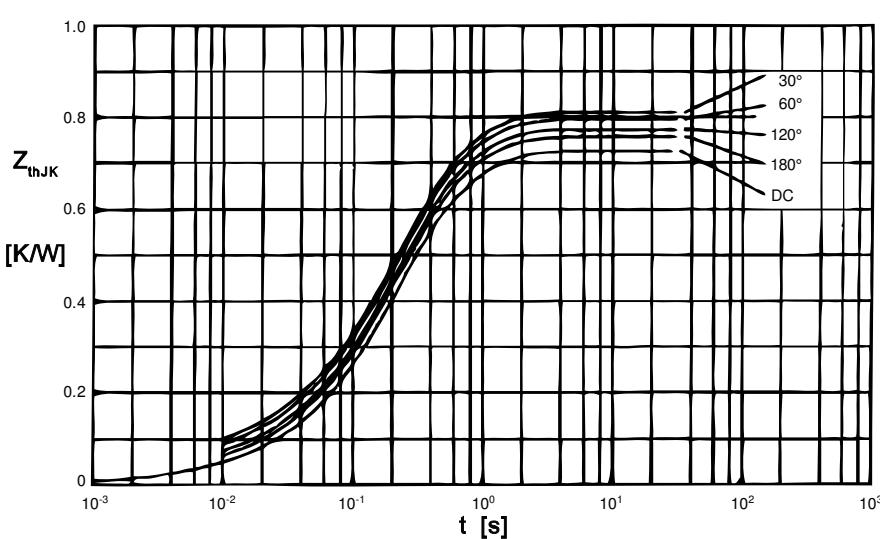


Fig. 10 Transient thermal impedance junction to heatsink (per thyristor)

$R_{thJK}$  for various conduction angles d:

d	$R_{thJK}$ [K/W]
DC	0.73
180°	0.75
120°	0.78
60°	0.80
30°	0.82

Constants for  $Z_{thJK}$  calculation:

i	$R_{thi}$ [K/W]	$t_i$ [s]
1	0.015	0.0035
2	0.026	0.0200
3	0.489	0.0195
4	0.200	0.6800

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